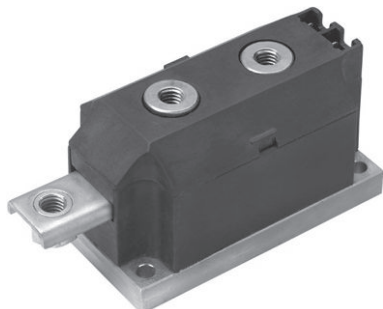


SCR/SCR and SCR/Diode (MAGN-A-PAK Power Modules), 170 A/250 A



MAGN-A-PAK

FEATURES

- High voltage
- Electrically isolated base plate
- 3500 V_{RMS} isolating voltage
- Industrial standard package
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL approved file E78996 
- Compliant to RoHS directive 2002/95/EC
- Designed and qualified for industrial level



RoHS
COMPLIANT

PRODUCT SUMMARY

$I_{T(AV)}$	170 A/250 A
-------------	-------------

DESCRIPTION

This new VSK series of MAGN-A-PAK modules uses high voltage power thyristor/thyristor and thyristor/diode in seven basic configurations. The semiconductors are electrically isolated from the metal base, allowing common heatsinks and compact assemblies to be built. They can be interconnected to form single phase or three phase bridges or as AC-switches when modules are connected in anti-parallel mode. These modules are intended for general purpose applications such as battery chargers, welders, motor drives, UPS, etc.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VSK.170..	VSK.250..	UNITS
$I_{T(AV)}$	85 °C	170	250	A
$I_{T(RMS)}$		377	555	
I_{TSM}	50 Hz	5100	8500	
	60 Hz	5350	8900	
I^2t	50 Hz	131	361	kA ² s
	60 Hz	119	330	
$I^2\sqrt{t}$		1310	3610	kA ² √s
V_{DRM}/V_{RRM}		Up to 1600	Up to 2000	V
T_J	Range	- 40 to 130		°C

VSK.170PbF, VSK.250PbF Series



Vishay Semiconductors

SCR/SCR and SCR/Diode
(MAGN-A-PAK Power Modules), 170 A/250 A

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS				
TYPE NUMBER	VOLTAGE CODE	V_{RRM}/V_{DRM} , MAXIMUM REPETITIVE PEAK REVERSE AND OFF-STATE BLOCKING VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM}/I_{DRM} AT 130 °C MAXIMUM mA
VSK.170-	04	400	500	50
	08	800	900	
	10	1000	1100	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	
VSK.250-	04	400	500	50
	08	800	900	
	10	1000	1100	
	12	1200	1300	
	14	1400	1500	
	16	1600	1700	
	18	1800	1900	
	20	2000	2100	60

ON-STATE CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			VSK.170	VSK.250	UNITS
Maximum average on-state current at case temperature	I _{T(AV)}	180° conduction, half sine wave			170	250	A
					85	85	°C
Maximum RMS on-state current	I _{T(RMS)}	As AC switch			377	555	A
Maximum peak, one-cycle on-state non-repetitive, surge current	I _{TSM}	t = 10 ms	No voltage reappplied	Sinusoidal half wave, initial T _J = T _J maximum	5100	8500	
		t = 8.3 ms			5350	8900	
		t = 10 ms	100 % V _{RRM} reappplied		4300	7150	
		t = 8.3 ms			4500	7500	
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reappplied		131	361	kA ² s
		t = 8.3 ms			119	330	
		t = 10 ms	100 % V _{RRM} reappplied		92.5	255	
		t = 8.3 ms			84.4	233	
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to 10 ms, no voltage reappplied			1310	3610	kA ² √s
Low level value or threshold voltage	V _{T(TO)1}	(16.7 % × π × I _{T(AV)} < I < π × I _{T(AV)}), T _J = T _J maximum			0.89	0.97	V
High level value of threshold voltage	V _{T(TO)2}	(I > π × I _{T(AV)} < I < π × I _{T(AV)}), T _J = T _J maximum			1.12	1.00	
Low level value on-state slope resistance	r _{t1}	(16.7 % × π × I _{T(AV)} < I < π × I _{T(AV)}), T _J = T _J maximum			1.34	0.60	mΩ
High level value on-state slope resistance	r _{t2}	(I > π × I _{T(AV)} < I < π × I _{T(AV)}), T _J = T _J maximum			0.96	0.57	
Maximum on-state voltage drop	V _{TM}	I _{TM} = π × I _{T(AV)} , T _J = T _J maximum, 180° conduction, average power = V _{T(TO)} × I _{T(AV)} + r _f × (I _{T(RMS)}) ²			1.60	1.44	V
Maximum holding current	I _H	Anode supply = 12 V, initial I _T = 30 A, T _J = 25 °C			500	500	mA
Maximum latching current	I _L	Anode supply = 12 V, resistive load = 1 Ω, gate pulse: 10 V, 100 μs, T _J = 25 °C			1000	1000	



VSK.170PbF, VSK.250PbF Series

SCR/SCR and SCR/Diode
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Vishay Semiconductors

SWITCHING

PARAMETER	SYMBOL	TEST CONDITIONS	VSK.170	VSK.250	UNITS
Typical delay time	t _d	T _J = 25 °C, gate current = 1 A dI _g /dt = 1 A/μs V _d = 0.67 % V _{DRM}	1.0		μs
Typical rise time	t _r		2.0		
Typical turn-off time	t _q	I _{TM} = 300 A; dI/dt = 15 A/μs; T _J = T _J maximum; V _R = 50 V; dV/dt = 20 V/μs; gate 0 V, 100 Ω	50 to 150		

BLOCKING

PARAMETER	SYMBOL	TEST CONDITIONS	VSK.170	VSK.250	UNITS
Maximum peak reverse and off-state leakage current	I_{RRM} , I_{DRM}	$T_J = T_J$ maximum	50	60	mA
RMS insulation voltage	V_{INS}	50 Hz, circuit to base, all terminals shorted, 25 $^\circ\text{C}$, 1 s	3000		V
Critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum, exponential to 67 % rated V_{DRM}	1000		V/ μs

TRIGGERING

PARAMETER	SYMBOL	TEST CONDITIONS		VSK.170	VSK.250	UNITS
Maximum peak gate power	P _{GM}	t _p ≤ 5 ms, T _J = T _J maximum		10.0		W
Maximum average gate power	P _{G(AV)}	f = 50 Hz, T _J = T _J maximum		2.0		
Maximum peak gate current	+ I _{GM}	t _p ≤ 5 ms, T _J = T _J maximum		3.0		A
Maximum peak negative gate voltage	- V _{GT}	t _p ≤ 5 ms, T _J = T _J maximum		5.0		V
Maximum required DC gate voltage to trigger	V _{GT}	T _J = - 40 °C	Anode supply = 12 V, resistive load; Ra = 1 Ω	4.0		
		T _J = 25 °C		3.0		
		T _J = T _J maximum		2.0		
Maximum required DC gate current to trigger	I _{GT}	T _J = - 40 °C	Anode supply = 12 V, resistive load; Ra = 1 Ω	350		mA
		T _J = 25 °C		200		
		T _J = T _J maximum		100		
Maximum gate voltage that will not trigger	V _{GD}	T _J = T _J maximum, rated V _{DRM} applied		0.25		V
Maximum gate current that willnot trigger	I _{GD}	T _J = T _J maximum, rated V _{DRM} applied		10.0		mA
Maximum rate of rise of turned-on current	dI/dt	T _J = T _J maximum, I _{TM} = 400 A, rated V _{DRM} applied		500		A/μs

THERMAL AND MECHANICAL SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS	VSK.170	VSK.250	UNITS
Junction operating and storage temperature range	T_J , T_{Stg}		- 40 to 130		$^\circ\text{C}$
Maximum thermal resistance, junction to case per junction	R_{thJC}	DC operation	0.17	0.125	K/W
Typical thermal resistance, case to heatsink per module	R_{thCS}	Mounting surface flat, smooth and greased	0.02	0.02	
Mounting torque $\pm 10\text{ } \%$	MAP to heatsink	A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound.	4 to 6		Nm
	busbar to MAP				
Approximate weight			500		g
			17.8		oz.
Case style			MAGN-A-PAK		

VSK.170PbF, VSK.250PbF Series



Vishay Semiconductors

SCR/SCR and SCR/Diode
(MAGN-A-PAK Power Modules), 170 A/250 A

ΔR CONDUCTION PER JUNCTION											
DEVICES	SINUSOIDAL CONDUCTION AT T _J MAXIMUM					RECTANGULAR CONDUCTION AT T _J MAXIMUM					UNITS
	180°	120°	90°	60°	30°	180°	120°	90°	60°	30°	
VSK.170-	0.009	0.010	0.010	0.020	0.032	0.007	0.011	0.015	0.020	0.033	K/W
VSK.250-	0.009	0.010	0.014	0.020	0.032	0.007	0.011	0.015	0.020	0.033	

Note

- Table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

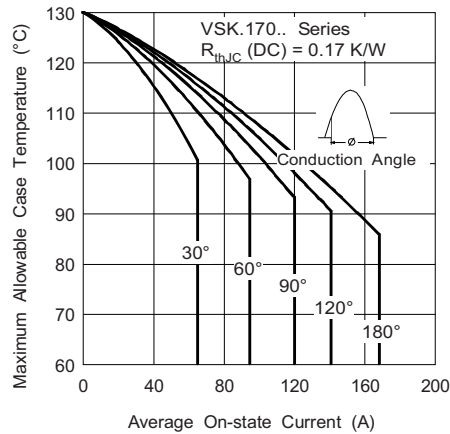


Fig. 1 - Current Ratings Characteristics

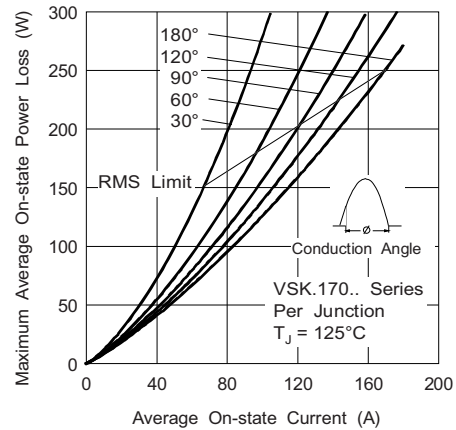


Fig. 3 - On-State Power Loss Characteristics

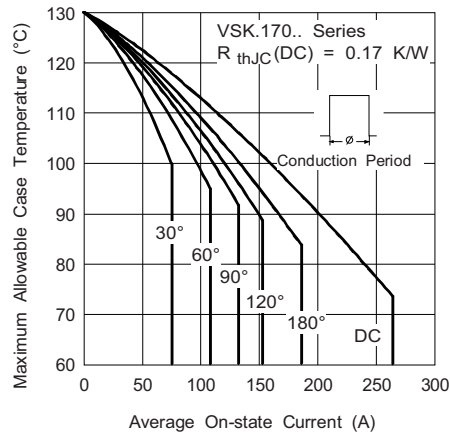


Fig. 2 - Current Ratings Characteristics

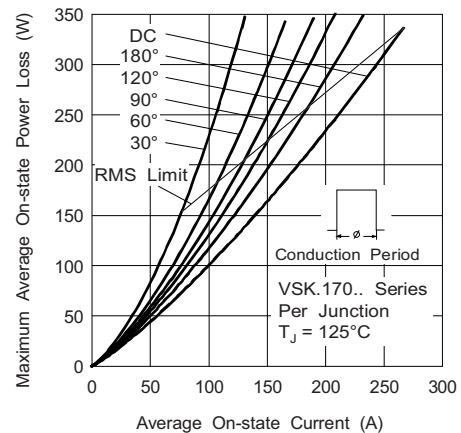


Fig. 4 - On-State Power Loss Characteristics



VSK.170PbF, VSK.250PbF Series

SCR/SCR and SCR/Diode
(MAGN-A-PAK Power Modules), 170 A/250 A

Vishay Semiconductors

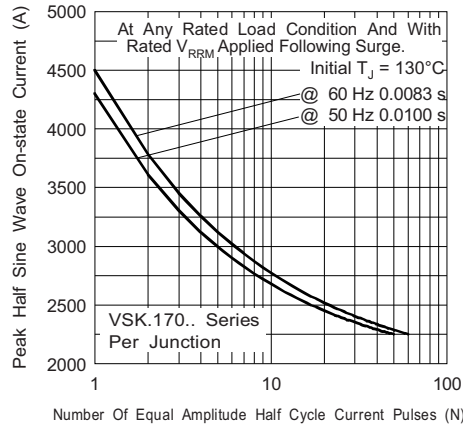


Fig. 5 - Maximum Non-Repetitive Surge Current

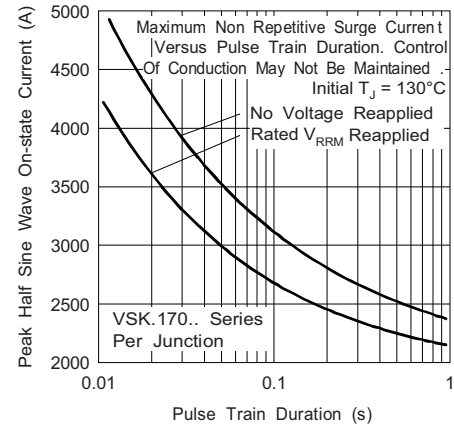


Fig. 6 - Maximum Non-Repetitive Surge Current

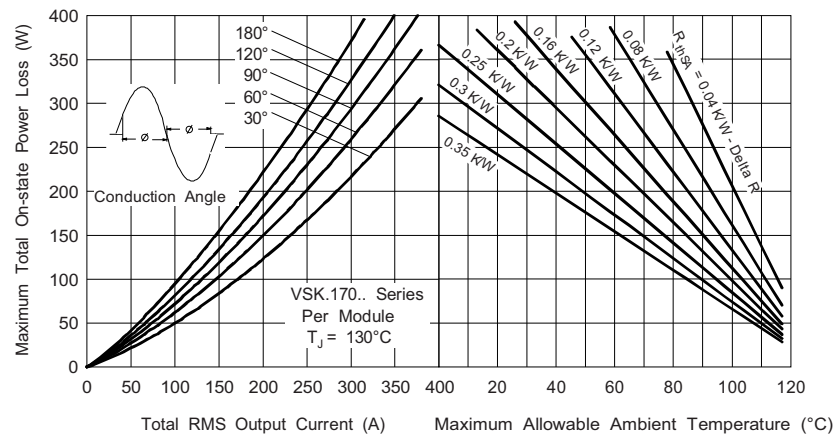


Fig. 7 - On-State Power Loss Characteristics

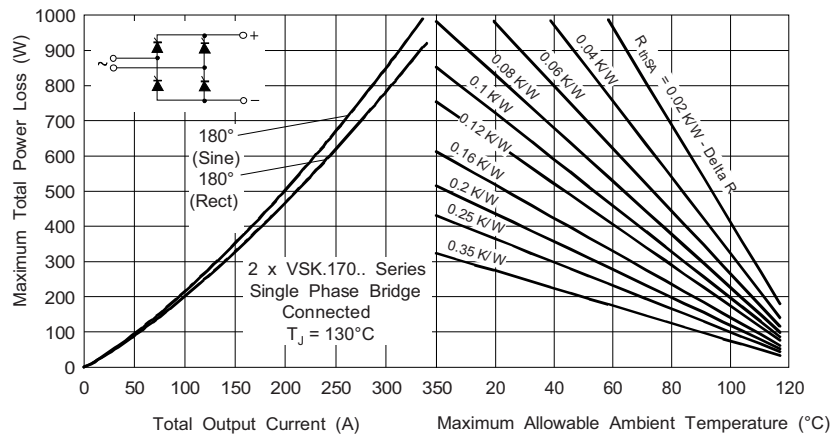


Fig. 8 - On-State Power Loss Characteristics

VSK.170PbF, VSK.250PbF Series

Vishay Semiconductors

SCR/SCR and SCR/Diode
(MAGN-A-PAK Power Modules), 170 A/250 A

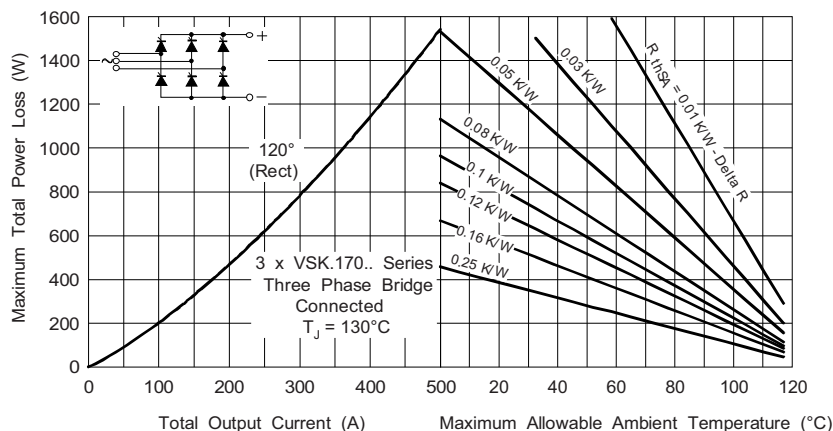


Fig. 9 - On-State Power Loss Characteristics

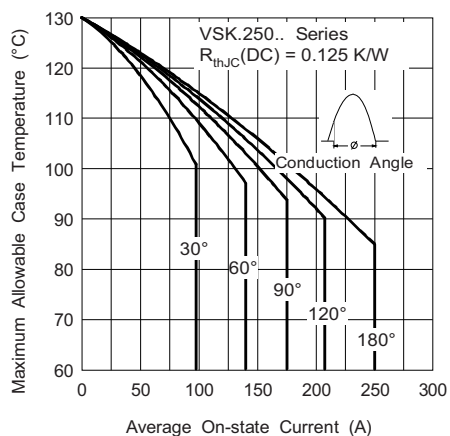


Fig. 10 - Current Ratings Characteristics

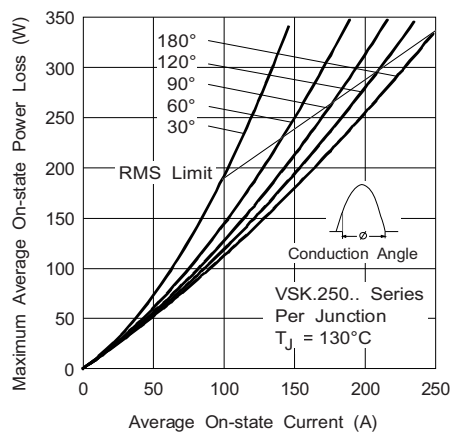


Fig. 12 - On-State Power Loss Characteristics

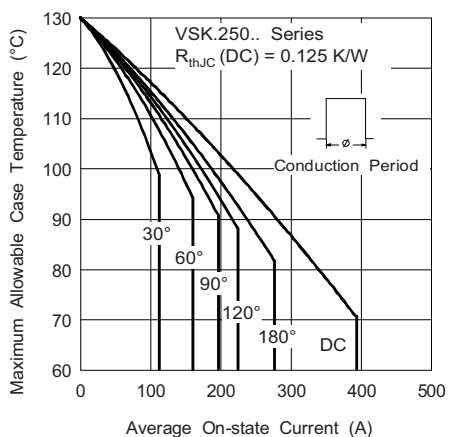


Fig. 11 - Current Ratings Characteristics

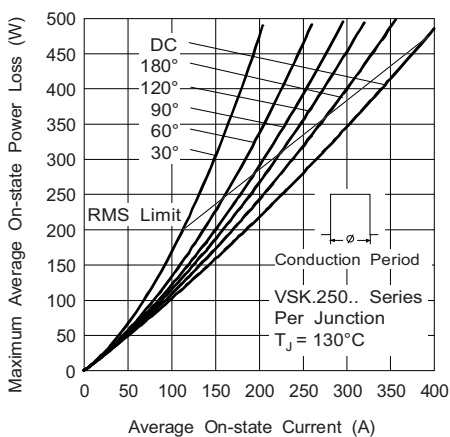


Fig. 13 - On-State Power Loss Characteristics

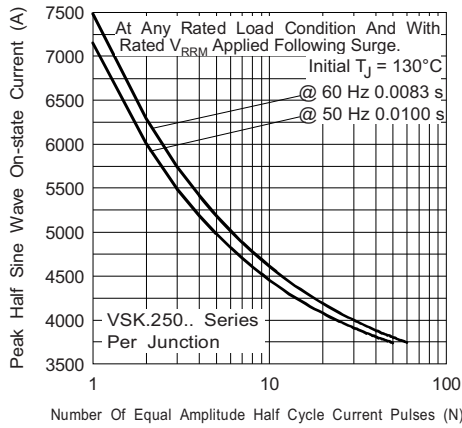


Fig. 14 - Maximum Non-Repetitive Surge Current

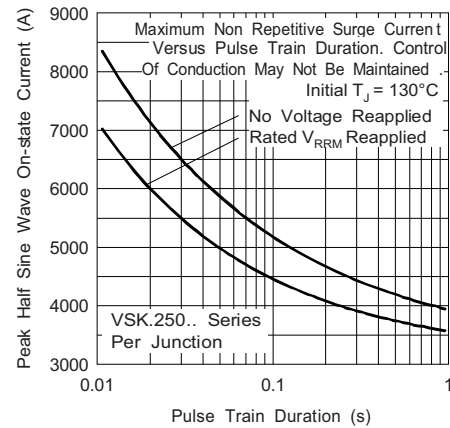


Fig. 15 - Maximum Non-Repetitive Surge Current

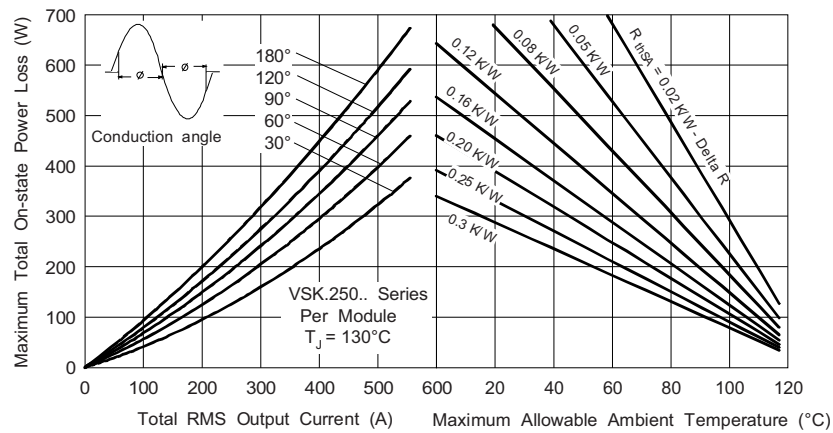


Fig. 16 - On-State Power Loss Characteristics

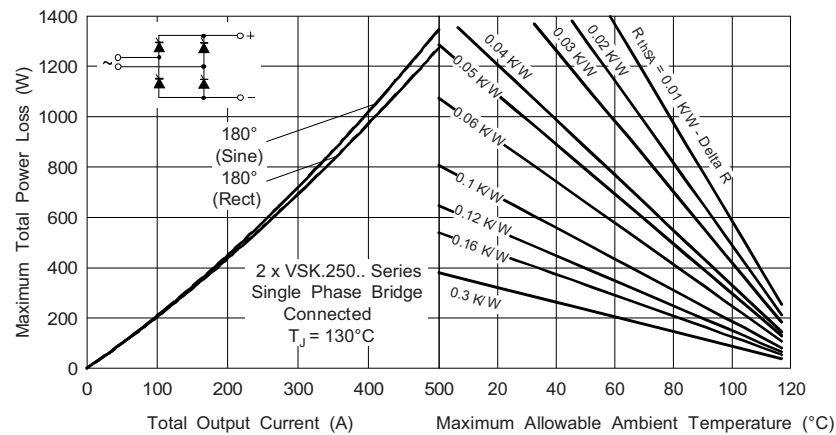


Fig. 17 - On-State Power Loss Characteristics

VSK.170PbF, VSK.250PbF Series

Vishay Semiconductors

SCR/SCR and SCR/Diode
(MAGN-A-PAK Power Modules), 170 A/250 A

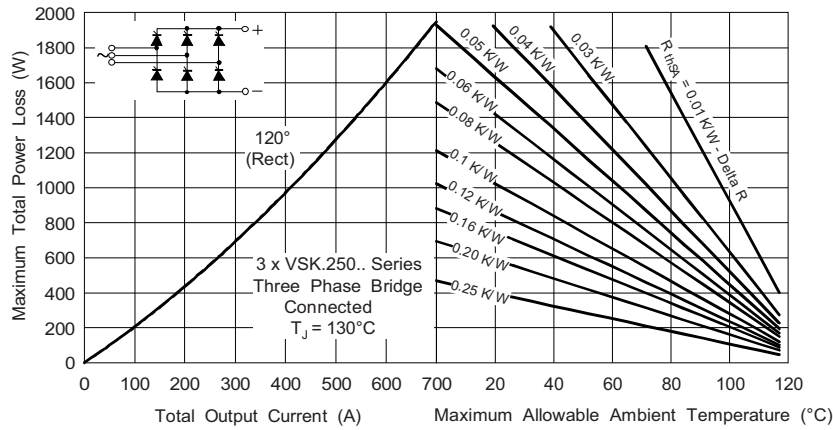


Fig. 18 - On-State Power Loss Characteristics

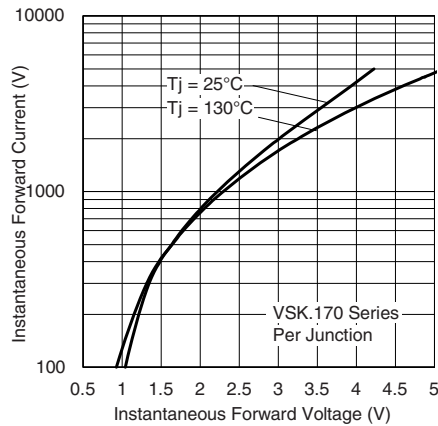


Fig. 19 - On-State Voltage Drop Characteristics

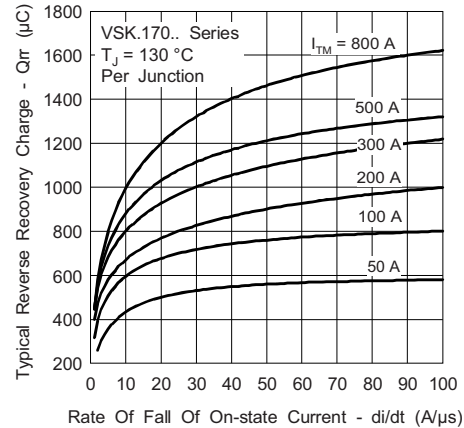


Fig. 21 - Reverse Recovery Charge Characteristics

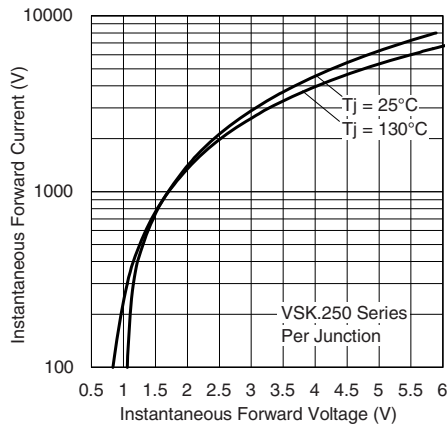


Fig. 20 - On-State Voltage Drop Characteristics

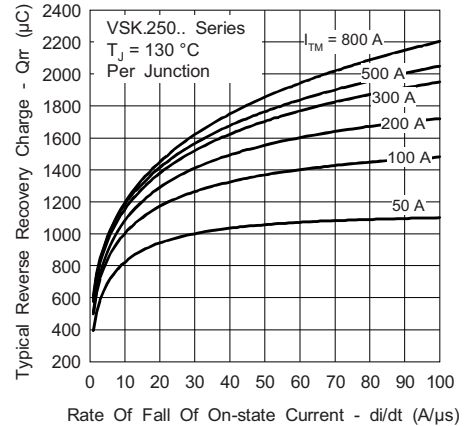


Fig. 22 - Reverse Recovery Charge Characteristics



VSK.170PbF, VSK.250PbF Series

SCR/SCR and SCR/Diode
(MAGN-A-PAK Power Modules), 170 A/250 A

Vishay Semiconductors

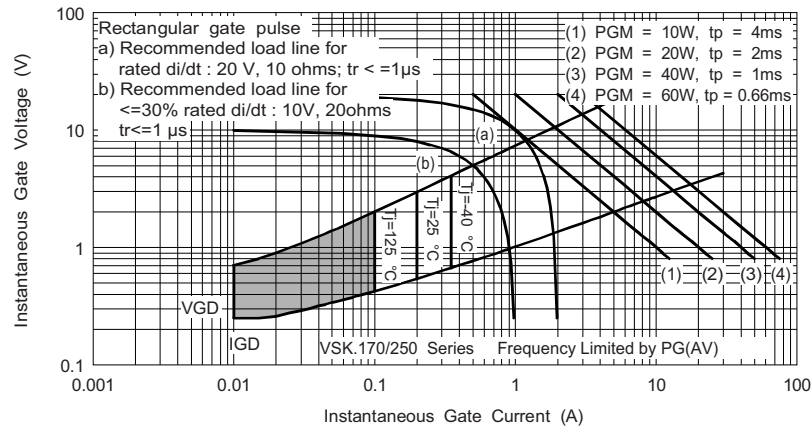


Fig. 23 - Gate Characteristics

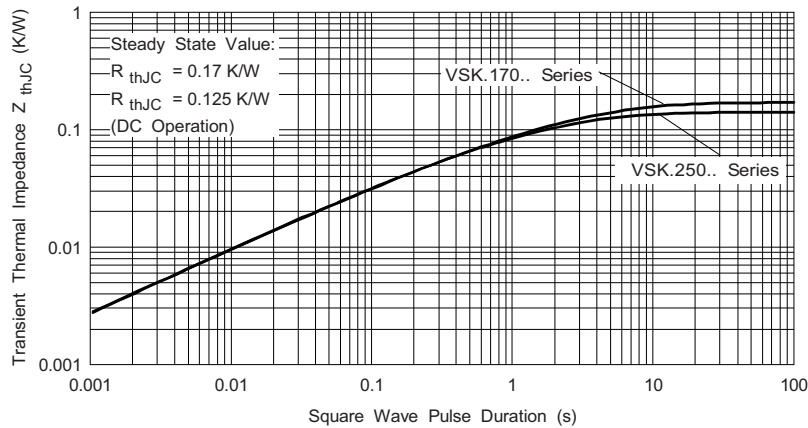


Fig. 24 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	VSK	T	250	-	20	PbF
	1	2	3		4	5

- 1 - Module type
- 2 - Circuit configuration (see dimensions - link at the end of datasheet)
- 3 - Current rating
- 4 - Voltage code x 100 = V_{RRM} (see Voltage Ratings table)
- 5 -
 - None = Standard production
 - PbF = Lead (Pb)-free

Note

- To order the optional hardware go to www.vishay.com/doc?95172

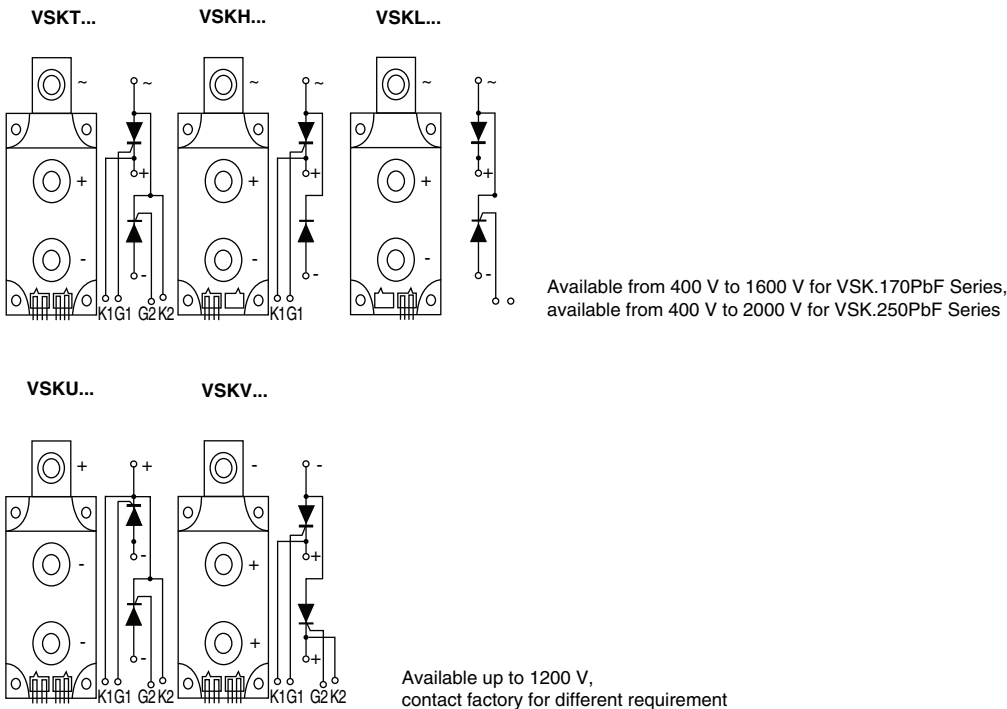
VSK.170PbF, VSK.250PbF Series



Vishay Semiconductors

SCR/SCR and SCR/Diode
(MAGN-A-PAK Power Modules), 170 A/250 A

CIRCUIT CONFIGURATION



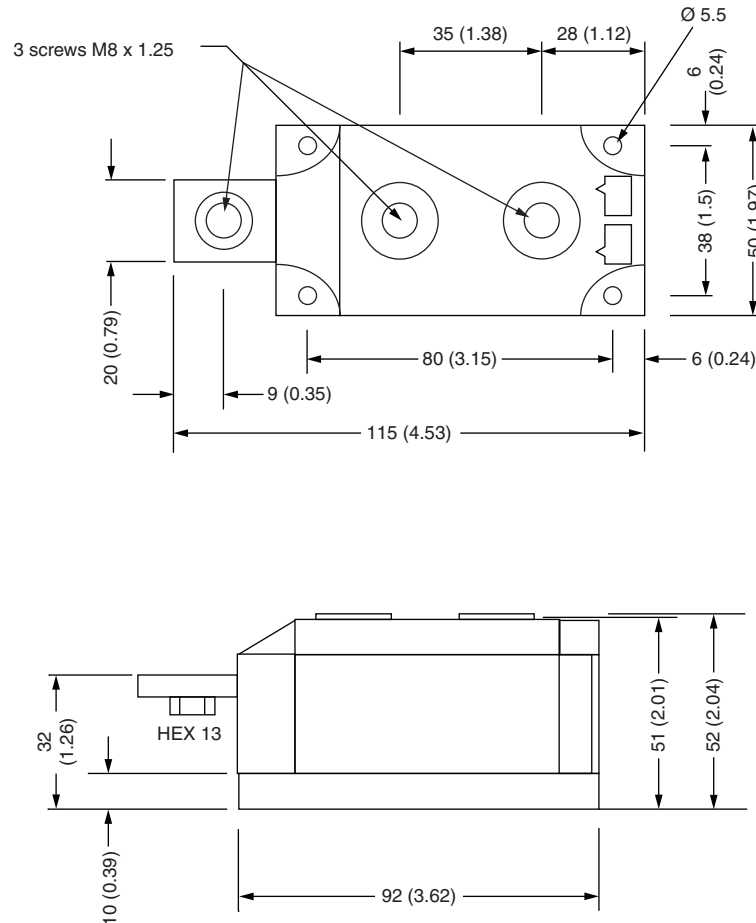
LINKS TO RELATED DOCUMENTS

Dimensions

www.vishay.com/doc?95086

MAGN-A-PAK

DIMENSIONS in millimeters (inches)



Notes

- Dimensions are nominal
- Full engineering drawings are available on request
- UL identification number for gate and cathode wire: UL 1385
- UL identification number for package: UL 94 V-0



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Vishay Intertechnology, Inc. hereby certifies that all its products that are identified as RoHS-Compliant fulfill the definitions and restrictions defined under Directive 2011/65/EU of The European Parliament and of the Council of June 8, 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment (EEE) - recast, unless otherwise specified as non-compliant.

Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

Mouser Electronics

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